

CD54HC195, CD74HC195

Data sheet acquired from Harris Semiconductor SCHS165E

September 1997 - Revised October 2003

High-Speed CMOS Logic 4-Bit Parallel Access Register

Features

- · Asynchronous Master Reset
- J, K, (D) Inputs to First Stage
- Fully Synchronous Serial or Parallel Data Transfer
- · Shift Right and Parallel Load Capability
- Complementary Output From Last Stage
- · Buffered Inputs
- Typical $f_{MAX} = 50MHz$ at $V_{CC} = 5V$, $C_L = 15pF$, $T_A = 25^{\circ}C$
- Fanout (Over Temperature Range)

 - Bus Driver Outputs15 LSTTL Loads
- Wide Operating Temperature Range . . . -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30%of V_{CC} at V_{CC} = 5V

Description

The device is useful in a wide variety of shifting, counting and storage applications. It performs serial, parallel, serial to parallel, or parallel to serial data transfers at very high speeds.

The two modes of operation, shift right (Q $_0$ -Q $_1$) and parallel load, are controlled by the state of the Parallel Enable (\overline{PE}) input. Serial data enters the first flip-flop (Q $_0$) via the J and \overline{K} inputs when the \overline{PE} input is high, and is shifted one bit in the direction Q $_0$ -Q $_1$ -Q $_2$ -Q $_3$ following each Low to High clock transition. The J and \overline{K} inputs provide the flexibility of the JK-type input for special applications and by tying the two pins together, the simple D-type input for general applications. The device appears as four common-clocked D flip-flops when the \overline{PE} input is Low. After the Low to High clock transition, data on the parallel inputs (D0-D3) is transferred to the respective Q $_0$ -Q $_3$ outputs. Shift left operation (Q $_3$ -Q $_2$) can be achieved by tying the Q $_n$ outputs to the Dn-1 inputs and holding the \overline{PE} input low.

All parallel and serial data transfers are synchronous, occurring after each Low to High clock transition. The 'HC195 series utilizes edge triggering; therefore, there is no restriction on the activity of the J, \overline{K} , Pn and \overline{PE} inputs for logic operations, other than set-up and hold time requirements. A Low on the asynchronous Master Reset (\overline{MR}) input sets all Q outputs Low, independent of any other input condition.

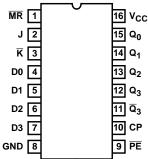
_____ Ordering Information

PART NUMBER	TEMP. RANGE (^O C)	PACKAGE		
CD54HC195F3A	-55 to 125	16 Ld CERDIP		
CD74HC195E	-55 to 125	16 Ld PDIP		
CD74HC195M	-55 to 125	16 Ld SOIC		
CD74HC195NSR	-55 to 125	16 Ld SOP		
CD74HC195PW	-55 to 125	16 Ld TSSOP		
CD74HC195PWR	-55 to 125	16 Ld TSSOP		
CD74HC195PWT	-55 to 125	16 Ld TSSOP		

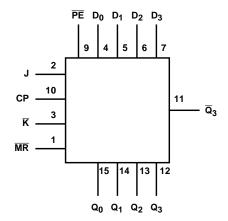
NOTE: When ordering, use the entire part number. The suffix R denotes tape and reel. The suffix T denotes a small-quantity reel of 250.

Plnout

CD54HC195 (CERDIP) CD74HC195 (PDIP, SOIC, SOP, TSSOP) TOP VIEW



Functional Diagram



TRUTH TABLE

			INP	UTS			ОИТРИТ						
OPERATING MODES	MR	СР	PE	J	K	Dn	Q ₀	Q ₁	Q ₂	Q ₃	\overline{Q}_3		
Asynchronous Reset	L	Х	Х	Х	Х	Х	L	L	L	L	Н		
Shift, Set First Stage	Н	1	h	h	h	Х	Н	90	q 1	q ₂	- q ₂		
Shift, Reset First Stage	Н	1	h	I	I	Х	L	90	91	q ₂	\bar{q}_2		
Shift, Toggle First Stage	Н	1	h	h	I	Х	\bar{q}_0	90	q 1	q ₂	- q ₂		
Shift, Retain First Stage	Н	1	h	I	h	Х	90	90	q 1	q ₂	- q ₂		
Parallel Load	Н	1	I	Х	Х	dn	d ₀	d ₁	d ₂	d3	d2		

H = High Voltage Level

L = Low Voltage Level,

X = Don't Care

^{↑ =} Transition from Low to High Level

I = Low Voltage Level One Set-up Time Prior to the Low to High Clock Transition

h = Low Voltage Level One Set-up Time prior to the High to Low Clock Transition,

 $dn (q_n)$ = Lower Case Letters Indicate the State of the Referenced Input (or output) One Set-up Time Prior to the Low to High Clock Transition.

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Absolute Maximum Ratings

DC Supply Voltage, V _{CC}	-0.5V to 7V
DC Input Diode Current, I _{IK}	
For $V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$	±20mA
DC Output Diode Current, IOK	
For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$	±20mA
DC Output Source or Sink Current per Output Pin, IO	
For $V_O > -0.5V$ or $V_O < V_{CC} + 0.5V$	±25mA
DC V _{CC} or Ground Current, I _{CC or} I _{GND}	±50mA

Thermal Information

Package Thermal Impedance, θ _{1Δ} (see Note 1):
E (PDIP) Package
M (SOIC) Package73°C/W
NS (SOP) Package
PW (TSSOP) Package 108°C/W
Maximum Junction Temperature
Maximum Storage Temperature Range65°C to 150°C
Maximum Lead Temperature (Soldering 10s)300°C
(SOIC - Lead Tips Only)

Operating Conditions

Temperature Range (T _A)55°C to 125°C
Supply Voltage Range, V _{CC}
HC Types2V to 6V
HCT Types
DC Input or Output Voltage, V _I , V _O
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

		TEST CONDITIONS				25°C		-40°C 1	O 85°C	-55°C TO 125°C		
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
High Level Input	V _{IH}	-	-	2	1.5	-	-	1.5	-	1.5	-	V
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input	V _{IL}	-	-	2	-	-	0.5	-	0.5	-	0.5	V
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output	V _{OH}	V _{IH} or V _{IL}	-0.02	2	1.9	-	-	1.9	-	1.9	-	V
/oltage CMOS Loads			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
OWIGO Edddo			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output			-	-	-	-	-	-	-	-	-	V
/oltage TL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
TTE Edad3			-5.2	6	5.48	-	-	5.34	-	5.2	-	V
Low Level Output	V _{OL}	V_{IH} or V_{IL}	0.02	2	-	-	0.1	-	0.1	-	0.1	V
Voltage CMOS Loads			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
OWICO LOAGS			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output			-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
TTE LOADS			5.2	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	IĮ	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μΑ
Quiescent Device Current	Icc	V _{CC} or GND	0	6	-	-	8	-	80	-	160	μΑ

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Prerequisite For Switching Function

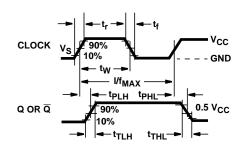
		TEST		25	°С	-40°C 1	O 85°C	-55°C T	-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS	
Clock Frequency	f _{MAX}	-	2	6	-	5	-	4	-	MHz	
			4.5	30	-	25	-	20	-	MHz	
			6	35	-	29	-	23	-	MHz	
MR Pulse Width	t _w	-	2	80	-	100	-	120	-	ns	
			4.5	16	-	20	-	24	-	ns	
			6	14	-	17	-	20	-	ns	
Clock Pulse Width	t _w	-	2	80	-	100	-	120	-	ns	
			4.5	16	-	20	-	24	-	ns	
			6	14	-	17	-	20	-	ns	
Set-up Time	t _{SU}	-	2	100	-	125	-	150	-	ns	
J, K, PE to Clock			4.5	20	-	25	-	30	-	ns	
			6	17	-	21	-	26	-	ns	
Hold Time	t _H	-	2	3	-	3	-	3	-	ns	
J, K, PE to Clock			4.5	3	-	3	-	3	-	ns	
			6	5	-	3	-	3	-	ns	
Removal Time,	t _{REM}	-	2	80	-	100	-	120	-	ns	
MR to Clock			4.5	16	-	20	-	24	-	ns	
			6	14	-	17	-	20	-	ns	

Switching Specifications Input t_r , $t_f = 6ns$

		TEST		25	°C	-40°C TO 85°C	-55°C TO 125°C	
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	TYP	MAX	MAX	MAX	UNITS
HC TYPES					-			
Propagation Delay, CP to	t _{PLH} , t _{PHL}	C _L = 50pF	2	·	175	220	265	ns
Output			4.5	-	35	44	53	ns
			6	-	30	37	45	ns
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	150	190	225	ns
MR toOutput			4.5	-	30	38	45	ns
			6	-	26	33	38	ns
utput Transition Times	t _{TLH} , t _{THL}	C _L = 50pF	2	-	75	95	110	ns
(Figure 1)			4.5	-	15	19	22	ns
			6	-	13	16	19	ns
Input Capacitance	C _{IN}	-	-	-	10	10	10	pF
CP to Q _n Propagation Delay	t _{PLH} , t _{PHL}	C _L = 15pF	5	14	-	-	-	ns
MR to Q _n	t _{PHL}	C _L = 15pF	5	13	-	-	-	ns
Maximum Clock Frequency	f _{MAX}	C _L = 15pF	5	50	-	-	-	MHz
Power Dissipation Capacitance (Notes 2, 3)	C _{PD}	C _L = 15pF		45	-	-	-	pF

- 2. C_{PD} is used to determine the dynamic power consumption, per flip-flop.
 3. P_D = V_{CC}² f_i + ∑ (C_L V_{CC}² + f_O) where f_i = Input Frequency, f_O = Output Frequency, C_L = Output Load Capacitance, V_{CC} = Supply Voltage.

Test Circuit and Waveforms



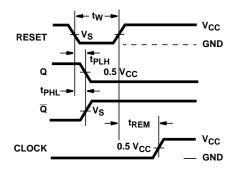


FIGURE 1. CLOCK PREREQUISITE AND PROPAGATION DELAYS AND OUTPUT TRANSITION TIMES

FIGURE 2. MASTER RESET PREREQUISITE AND PROPAGATION DELAYS

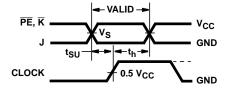


FIGURE 3. J, $\overline{\mathbf{K}}$, OR PARALLEL ENABLE PREREQUISITE TIMES





10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty		Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Q.y	(2)	(6)	(3)		(4/5)	
CD74HC195E	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC195E	Samples
CD74HC195EE4	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC195E	Samples
CD74HC195M	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC195M	Samples
CD74HC195M96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC195M	Samples
CD74HC195M96G4	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC195M	Samples
CD74HC195NSR	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC195M	Samples
CD74HC195PW	ACTIVE	TSSOP	PW	16	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HJ195	Samples
CD74HC195PWG4	ACTIVE	TSSOP	PW	16	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HJ195	Samples
CD74HC195PWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HJ195	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.



PACKAGE OPTION ADDENDUM

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(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

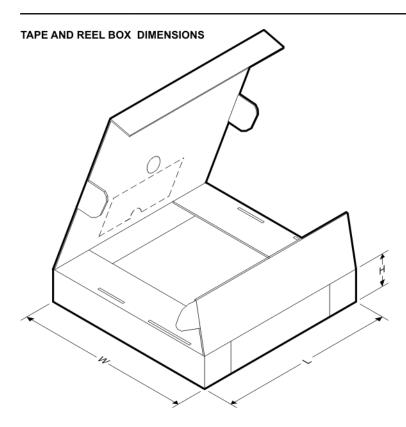
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device Device	Package Type	Package Drawing		SPQ	Reel Diameter	Reel Width	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
					` '	W1 (mm)						
CD74HC195M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HC195NSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD74HC195PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC195M96	SOIC	D	16	2500	333.2	345.9	28.6
CD74HC195NSR	SO	NS	16	2000	853.0	449.0	35.0
CD74HC195PWR	TSSOP	PW	16	2000	853.0	449.0	35.0

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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